

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese

FAIRCHILD

NC7SZ373 TinyLogic® UHS D-Type Latch with 3-STATE Output

General Description

Features

- Space saving SC70 6-lead package
- Ultra small MicroPak[™] leadless package
- Ultra High Speed; t_{PD} 2.6 ns Typ into 50 pF at 5V V_{CC}

- High Output Drive; ±24 mA at 3V V_{CC}
- Broad V_{CC} Operating Range; 1.65V to 5.5V
- Matches the performance of LCX when operated at $3.3V V_{CC}$
- Power down high impedance inputs/output
- Overvoltage tolerant inputs facilitate 5V to 3V translation
- Patented noise/EMI reduction circuitry implemented

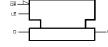
Ordering Code:

EAIRCI SEMICOND NC7SZ3 FinyLog	UCTOR IM 73	S D-Typ	e Latch with 3-STATE	Revised August 2004
CMOS Latch wit High Speed Ser SC70 6-lead pa advanced CMOS with high output dissipation over device is specifie The inputs and ou nputs tolerate vo ating voltage. The when Latch Enal data that meets ti	s a single posi h 3-STATE ou ies of TinyLog ickage. The of technology to drive while ma a very broad d to operate ow ttput are high in ttages up to 7V e latch appea ole (LE) is HIC ne setup time is	h tive edge-triggere tput from Fairchi ic® in the space device is fabrice achieve ultra hi intaining low sta V_{CC} operating ra- er the 1.65V to 5.1, independent of V independent of V is transparent to H. When LE is is a latched. The ou S-STATE condition	ild's Ultra Ultra small MicroPak™ lead e saving ated with gh speed Ultra High Speed; t _{PD} 2.6 m High Output Drive; ±24 mA Broad V _{CC} Operating Rang Matches the performance o 3.3V V _{CC} Power down high impedanc V _{CC} oper- the data LOW, the Patented noise/EMI reduction	less package s Typ into 50 pF at 5V V_{CC} at 3V V_{CC} le; 1.65V to 5.5V of LCX when operated at ce inputs/output facilitate 5V to 3V translation
Ordering (Code: Package	Product Code		
Number	Number	Top Mark	Package Description	Supplied As
	MAA06A	Z73	6-Lead SC70, EIAJ SC88, 1.25mm Wide	3k Units on Tape and Reel
IC7SZ373P6X IC7SZ373L6X	MAC06A	D4	6-Lead MicroPak, 1.0mm Wide	5k Units on Tape and Reel

TinyLogic® is a registered trademark of Fairchild Semiconductor Corporation. MicroPak™ is a trademark of Fairchild Semiconductor Corporation.

NC7SZ373

Logic Symbol



Pin Descriptions

Pin Names	Description	
D	Data Input	
LE	Latch Enable Input	
OE	Output Enable Input	
Q	Latch Output	

Function Table

		Output		
	LE	D	OE	Q
	Н	L	L	L
	Н	H L	L	Н
	L	Х	L	Q _{n-1}
	Х	Х	н	Z
HIGH	Logic Level	X = Immate	rial	

H = HIGH Logic Level X = Immaterial L = LOW Logic Level Z = HIGH Impedance

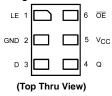
 Q_{n-1} = Previous state prior to HIGH-to-LOW transition of latch enable

Connection Diagrams Pin Assignments for SC70 Life of the field of th

AAA = Product Code Top Mark - see ordering code

Note: Orientation of Top Mark determines Pin One location. Read the top product code mark left to right, Pin One is the lower left pin.(see diagram).

Pad Assignments for MicroPak



Absolute Maximum Ratings(Note 1)							
Supply Voltage (V _{CC})	-0.5V to +7.0V						
DC Input Voltage (V _{IN})	-0.5V to +7.0V						
DC Output Voltage (V _{OUT})	-0.5V to +7.0V						
DC Input Diode Current (IIK)							
V _{IN} < 0V	-50 mA						
DC Output Diode Current (I _{OK})							
V _{OUT} < 0V	-50 mA						
DC Output (I _{OUT}) Source/Sink Current	±50 mA						
DC V _{CC} /GND Current (I _{CC} /I _{GND})	±50 mA						
Storage Temperature Range (T _{STG})	–65°C to +150°C						
Junction Temperature under Bias (T_J)	150°C						
Junction Lead Temperature (T _L)							
(Soldering, 10 seconds)	260°C						
Power Dissipation (P _D) @+85°C	180 mW						

Recommended Operating Conditions (Note 2) Power Supply 1.65V to 5.5V Operating (V_{CC}) 1.5V to 5.5V Data Retention 0V to 5.5V Input Voltage (V_{IN}) Output Voltage (V_{OUT}) Active State 0V to V_{CC} 3-STATE 0V to 5.5V Input Rise and Fall Time (t_r, t_f) V_{CC} = 1.8V, 2.5V \pm 0.2V 0 to 20 ns/V $V_{CC}=3.3V\pm0.3V$ 0 to 10 ns/V $V_{CC}=5.5V\pm0.5V$ 0 to 5 ns/V Operating Temperature (T_A) -40°C to +85°C 350° C/W Thermal Resistance (θ_{JA}) Note 1: The "Absolute Maximum Ratings": are those values beyond which the safety of the device cannot be guaranteed. The device should not be

NC7SZ373

operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}		$T_A = +25^{\circ}$	С	$\textbf{T}_{\textbf{A}}=-40^{\circ}\textbf{C}$ to $+85^{\circ}\textbf{C}$		Unit	Conditions	
Symbol	i arameter	(V)	Min	Тур	Max	Min	Max	Unit		nations
VIH	HIGH Level Control	1.65 to 1.95	0.75 V _{CC}			$0.75 \ V_{CC}$		v		
	Input Voltage	2.3 to 5.5	0.7 V _{CC}			0.7 V _{CC}		v		
VIL	LOW Level Control	1.65 to 1.95			0.25 V _{CC}		0.25 V _{CC}	v		
	Input Voltage	2.3 to 5.5			0.3 V _{CC}		0.3 V _{CC}	v		
V _{OH}	HIGH Level Control	1.65	1.55	1.65		1.55				
	Output Voltage	1.8	1.7	1.8		1.7				
		2.3	2.2	2.3		2.2				$I_{OH} = -100 \ \mu A$
		3.0	2.9	3.0		2.9			$V_{IN} = V_{IH}$	
		4.5	4.4	4.5		4.4		v		
		1.65	1.24	1.52		1.29		v		$I_{OH} = -4 \text{ mA}$
		2.3	1.9	2.15		1.9				$I_{OH} = -8 \text{ mA}$
		3.0	2.4	2.8		2.4				$I_{OH} = -16 \text{ mA}$
		3.0	2.3	2.68		2.3				$I_{OH} = -24 \text{ mA}$
		4.5	3.8	4.2		3.8				I _{OH} = -32 mA
V _{OL}	LOW Level Control	1.65		0.0	0.08		0.0			
	Output Voltage	1.8		0.0	0.1		0.1			
		2.3		0.0	0.1		0.1			$I_{OL}=100\;\mu A$
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1	v		
		1.65		0.08	0.24		0.24	v	$V_{IN} = V_{IL}$	$I_{OL} = 4 \text{ mA}$
		2.3		0.10	0.3		0.3			$I_{OL} = 8 \text{ mA}$
		3.0		0.15	0.4		0.4			$I_{OL} = 16 \text{ mA}$
		3.0		0.22	0.55		0.55			$I_{OL} = 24 \text{ mA}$
		4.5		0.22	0.55		0.55			$I_{OL} = 32 \text{ mA}$
I _{IN}	Input Leakage Current	0 to 5.5			±0.1		±1.0	μΑ	$0 \leq V_{IN} \leq$	5.5V
I _{OZ}	3-STATE	1.65 to 5.5			±0.5		±5.0	μA	$V_{IN} = V_{IL}$	or V _{IH}
	Output Leakage	1.05 10 5.5			±0.5		±3.0	μА	$0 \le V_{OUT}$	≤ 5.5V
I _{OFF}	Power-Off Leakage Current	0.0			1.0		10	μA	V _{IN} or V _O	_{UT} = 5.5V
I _{CC}	Quiescent Supply Current	1.65 to 5.5			1.0		10	μA	V _{IN} = 5.5 ^V	/, GND

0	Demonstra	V_{CC} $T_{A} = +25^{\circ}C$ $T_{A} = -40^{\circ}C$		C to +85°C	11-11-	O an alltilana	Figur			
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Units	Conditions	Numb
t _{PLH}	Propagation Delay	1.65	2.0	9.0	15.0	2.0	16.0			
t _{PHL}	D to Q	1.8	2.0	6.1	10.0	2.0	10.5			_
		2.5 ± 0.2	1.5	3.6	6.5	1.6	6.8		$C_L = 15 \text{ pF}$	Figu 1,
		3.3 ± 0.3	1.0	2.7	4.6	1.2	5.0	ns	$R_D = 1 M\Omega$.,
		5.0 ± 0.5	1.0	2.0	3.4	1.0	3.7		S ₁ = Open	
		3.3 ± 0.3	1.5	3.3	5.5	1.5	6.2		C _L = 50 pF	Figu
		5.0 ± 0.5	1.0	2.6	4.3	1.3	4.8		$R_D = 500\Omega$, $S_1 = Open$	ĭ,
t _{PLH}	Propagation Delay	1.65	2.0	9.0	1.45	2.0	15.0			
t _{PHL}	LE to Q	1.8	2.0	6.0	9.6	2.0	10.0			
		2.5 ± 0.2	1.8	3.5	6.1	1.5	6.6		C _L = 15 pF	Figu 1,
		3.3 ± 0.3	1.3	2.6	4.4	1.0	4.8	ns	$R_D = 1 M\Omega$	',
		5.0 ± 0.5	1.0	2.0	3.2	0.8	3.5		S ₁ = Open	
		3.3 ± 0.3	1.5	3.3	5.3	1.5	6.2		C _L = 50 pF	Figu
		5.0 ± 0.5	1.3	2.6	4.2	1.2	4.6		$R_D = 500\Omega$, $S_1 = Open$	Ĩ,
t _{PZL}	Output Enable Time	1.65	2.0	9.0	13.5	2.0	14.6			
t _{PZH}		1.8	2.0	6.0	9.0	2.0	9.5		$C_L = 50 \text{ pF}, \text{ V}_I = 2x \text{ V}_{CC}$	Figures 1, 4
		2.5 ± 0.2	2.0	3.7	6.0	1.8	6.6	ns	$R_U, R_D = 500\Omega$	
		3.3 ± 0.3	1.5	2.8	5.0	1.4	5.3		$S1 = GND$ for t_{PZH}	.,
		5.0 ± 0.5	1.0	2.2	3.7	1.0	3.9		$S1 = V_I$ for t_{PZL}	
t _{PLZ}	Output Disable Time	1.65	2.0	7.7	12.0	2.0	13.0			
t _{PHZ}		1.8	2.0	5.1	8.0	2.0	8.5		$C_L = 50 \text{ pF}, V_I = 2x V_{CC}$	
		2.5 ± 0.2	2.0	3.5	6.0	1.8	6.3	ns	$R_U, R_D = 500\Omega$	Figu 1,
		3.3 ± 0.3	1.5	2.8	4.5	1.4	4.7		$S_1 = GND$ for t_{PHZ}	.,
		5.0 ± 0.5	1.0	2.3	3.7	1.0	3.9		$S_1 = V_I$ for t_{PLZ}	
t _S	Setup Time,	2.5 ± 0.2				2.0			C _L = 50 pF	
	D to LE	3.3 ± 0.3				1.5		ns	$R_D = 500 \Omega$, $S_1 = Open$	Figu 1,
		5.0 ± 0.5				1.5				.,
t _H	Hold Time,	2.5 ± 0.2				1.5			$C_L = 50 \text{ pF}$	_
	D to LE	3.3 ± 0.3				1.5		ns	$R_D = 500 \ \Omega, \ S_1 = Open$	Figu 1,
		5.0 ± 0.5				1.5				· · ,
t _W	Pulse Width, LE	2.5 ± 0.2				3.0				1
		3.3 ± 0.3				3.0		ns	C _L = 50 pF	Figu 1,
		5.0 ± 0.5				3.0			$R_D = 500 \Omega$, $S_1 = Open$	· · ·

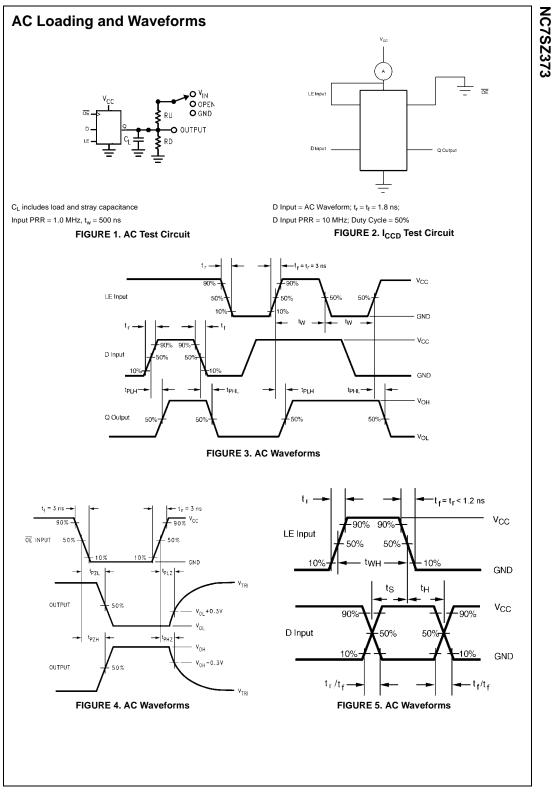
Capacitance (Note 3)

Symbol	Parameter	Тур	Max	Units	Conditions
C _{IN}	Input Capacitance	3		pF	$V_{CC} = Open, V_{IN} = 0V \text{ or } V_{CC}$
C _{OUT}	Output Capacitance	4		pF	V_{CC} = 3.3V, V_{IN} = 0V or V_{CC}
C _{PD}	Power Dissipation Capacitance	14		рF	V _{CC} = 3.3V
	(Note 4)	17			$V_{CC} = 5.0V$

Note 3: $T_A = +25C$, f = 1 MHz.

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 2) C_{PD} is related to I_{CCD} dynamic operating current by the expression:

 $\mathsf{I}_{\mathsf{CCD}} = (\mathsf{C}_{\mathsf{PD}})(\mathsf{V}_{\mathsf{CC}})(\mathsf{f}_{\mathsf{IN}}) + (\mathsf{I}_{\mathsf{CC}}\mathsf{static}).$

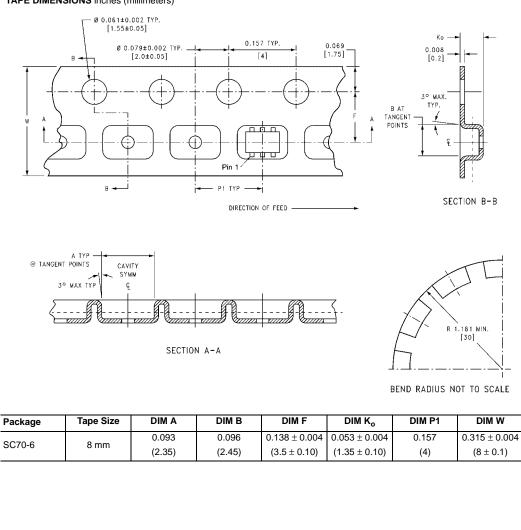


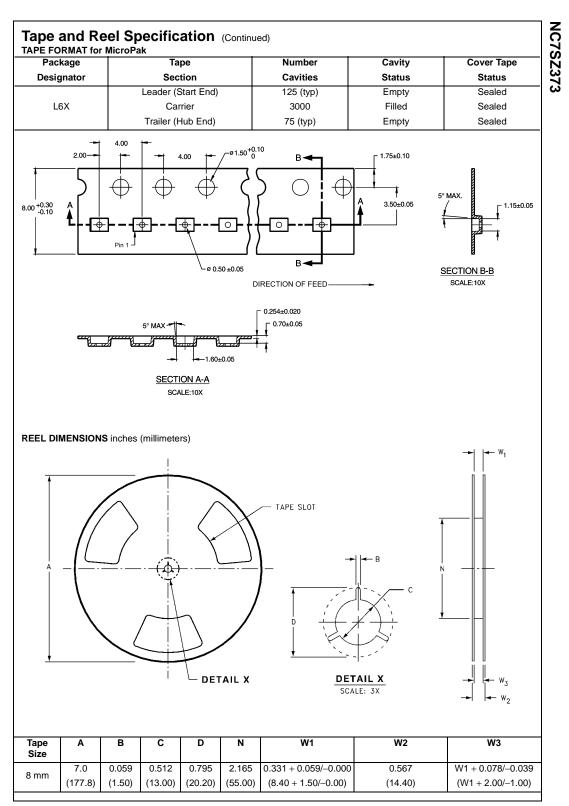


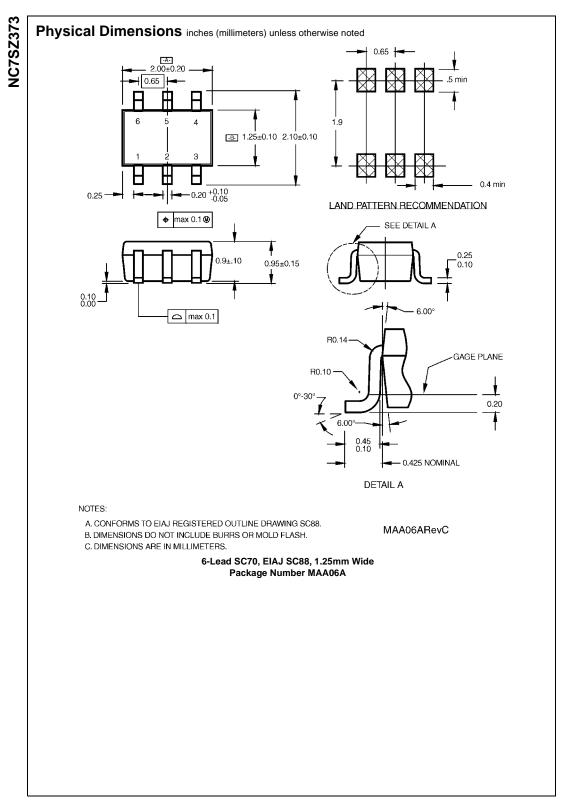
Tape and Reel Specification

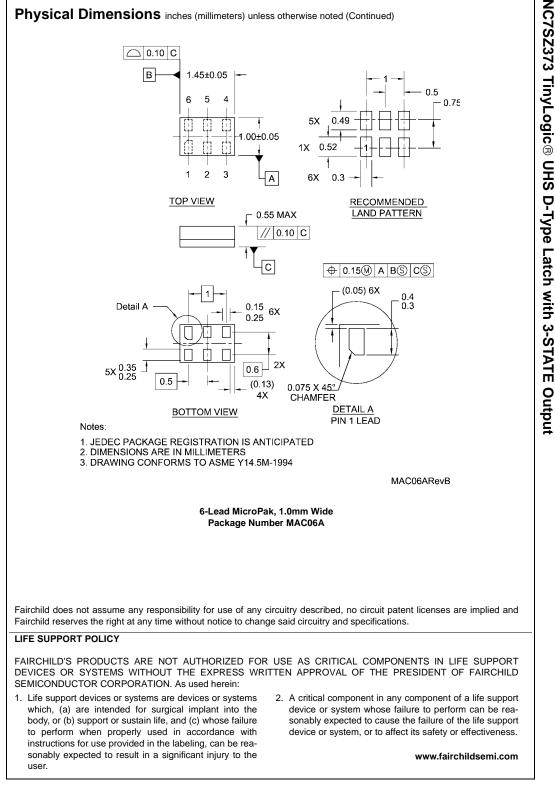
5	TAPE FORMAT for S	SC70			
	Package	Таре	Number	Cavity	Cover Tape
2	Designator	Section	Cavities	Status	Status
-		Leader (Start End)	125 (typ)	Empty	Sealed
	P6X	Carrier	3000	Filled	Sealed
		Trailer (Hub End)	75 (typ)	Empty	Sealed

TAPE DIMENSIONS inches (millimeters)









ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly ori indirectly, any claim of personal injury or death

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: <u>NC7SZ373P6</u> NC7SZ373P6X NC7SZ373L6X





Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.З, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж: moschip.ru moschip.ru_4

moschip.ru_6 moschip.ru_9